

DATA SHEET

TZA3041AHL; TZA3041BHL; TZA3041U Gigabit Ethernet/Fibre Channel laser drivers

Product specification
Supersedes data of 2000 Feb 22

2002 Aug 13

Gigabit Ethernet/Fibre Channel laser drivers

TZA3041AHL; TZA3041BHL; TZA3041U

FEATURES

- 1.2 Gbits/s data input, both Current Mode Logic (CML) and Positive Emitter Coupled Logic (PECL) compatible; maximum 800 mV (p-p)
- Adaptive laser output control with dual loop, stabilizing optical 1 and 0 levels
- Optional external control of laser modulation and biasing currents (non-adaptive)
- Automatic laser shutdown
- Few external components required
- Rise and fall times of 120 ps (typical value)
- Jitter <50 mUI (p-p)
- RF output current sinking capability of 60 mA
- Bias current sinking capability of 90 mA
- Power dissipation of 430 mW (typical value)
- Low cost LQFP32 5 × 5 plastic package
- Single 5 V power supply.

TZA3041AHL

- Laser alarm output for signalling extremely low and high bias current conditions.

TZA3041BHL

- Extra 1.2 Gbits/s loop mode input; both CML and PECL compatible.

TZA3041U

- Bare die version with combined bias alarm and loop mode functionality.

APPLICATIONS

- Gigabit Ethernet/Fibre Channel optical transmission systems
- Gigabit Ethernet/Fibre Channel optical laser modules.

GENERAL DESCRIPTION

The TZA3041AHL, TZA3041BHL and TZA3041U are fully integrated laser drivers for Gigabit Ethernet/Fibre Channel (1.2 Gbits/s) systems, incorporating the RF path between the data multiplexer and the laser diode. Since the dual loop bias and modulation control circuits are integrated on the IC, the external component count is low. Only decoupling capacitors and adjustment resistors are required.

The TZA3041AHL features an alarm function for signalling extreme bias current conditions. The alarm low and high threshold levels can be adjusted to suit the application using only a resistor or a current Digital-to-Analog Converter (DAC).

The TZA3041BHL is provided with an additional RF data input to allow remote system testing (loop mode).

The TZA3041U is a bare die version for use in compact laser module designs. The die contains 40 pads and features the combined functionality of the TZA3041AHL and the TZA3041BHL.

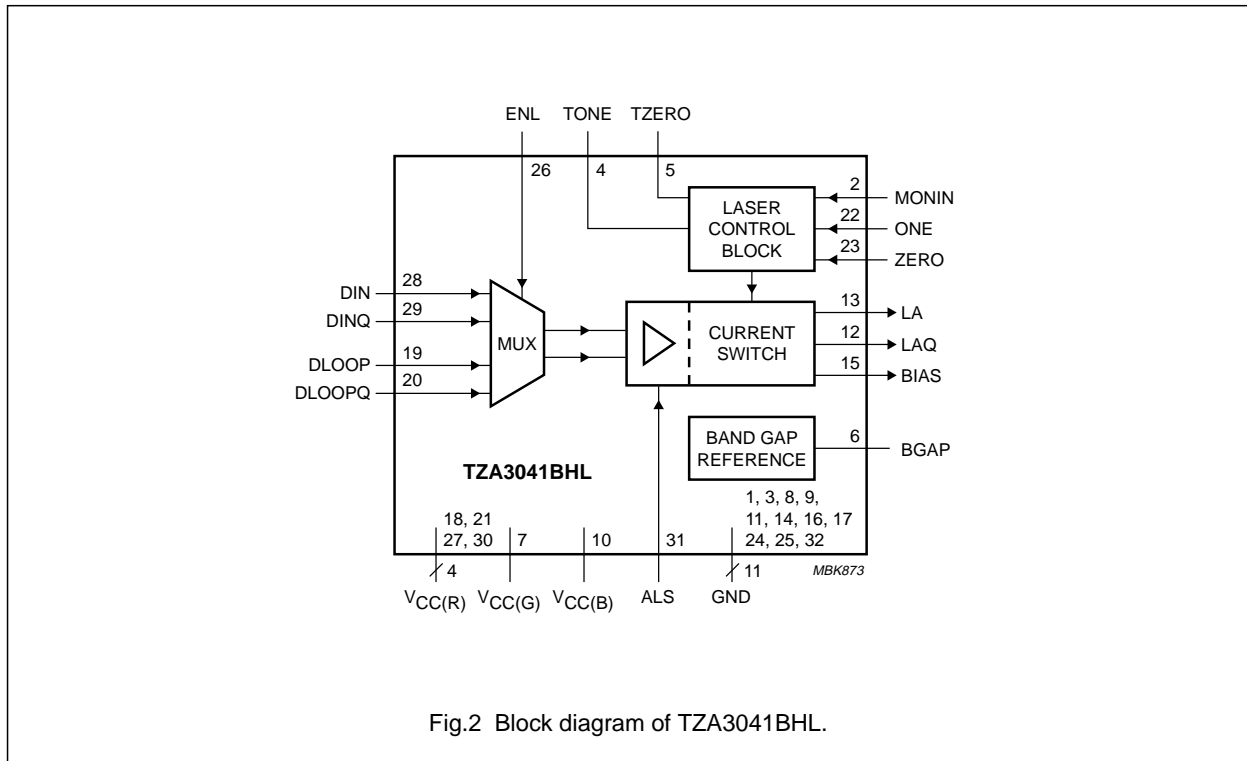
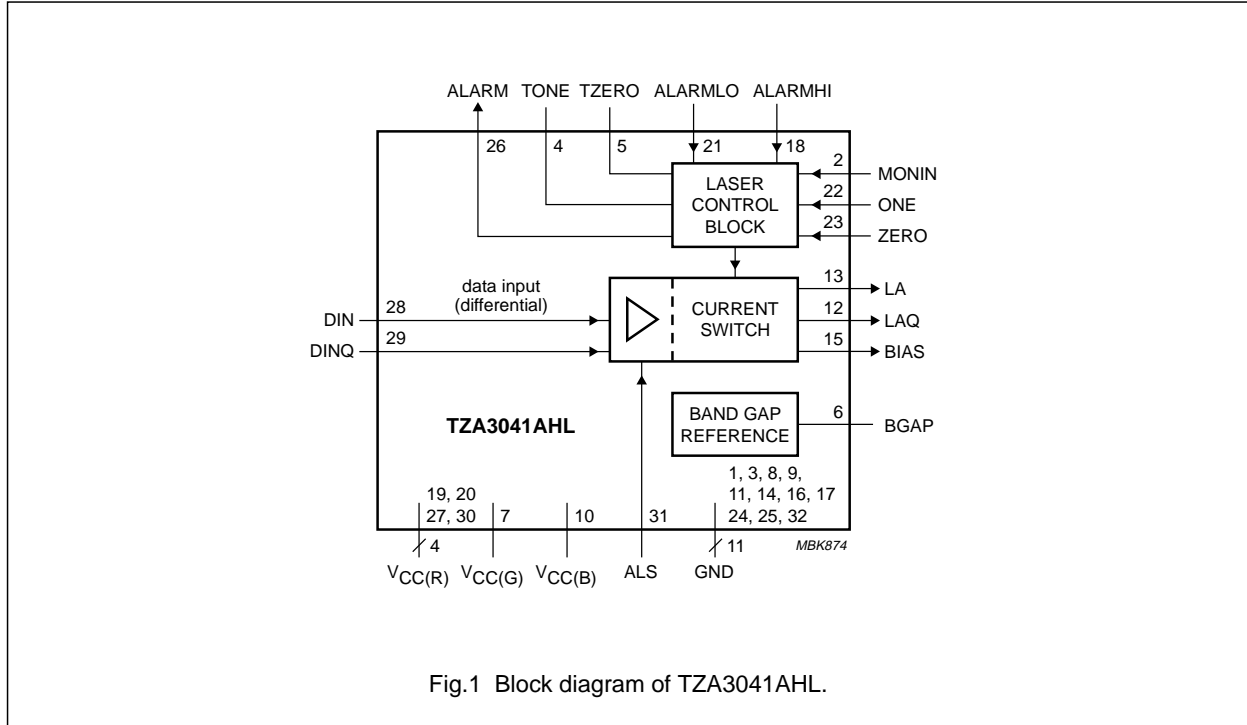
ORDERING INFORMATION

TYPE NUMBER	PACKAGE		
	NAME	DESCRIPTION	VERSION
TZA3041AHL	LQFP32	plastic low profile quad flat package; 32 leads; body 5 × 5 × 1.4 mm	SOT401-1
TZA3041BHL			
TZA3041U	–	bare die; 2000 × 2000 × 380 μm	–

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BLOCK DIAGRAM



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PINNING

SYMBOL	PIN		PAD	DESCRIPTION
	TZA3041AHL	TZA3041BHL	TZA3041U	
GND	1	1	1	ground
MONIN	2	2	2	monitor photodiode current input
GND	3	3	3	ground
IGM	–	–	4	not connected
TONE	4	4	5	connection for external capacitor used for setting optical 1 control loop time constant (optional)
TZERO	5	5	6	connection for external capacitor used for setting optical 0 control loop time constant (optional)
BGAP	6	6	7	connection for external band gap decoupling capacitor
V _{CC(G)}	7	7	8	supply voltage (green domain); note 1
V _{CC(G)}	–	–	9	supply voltage (green domain); note 1
GND	8	8	10	ground
GND	9	9	11	ground
V _{CC(B)}	10	10	12	supply voltage (blue domain); note 2
V _{CC(B)}	–	–	13	supply voltage (blue domain); note 2
GND	11	11	14	ground
LAQ	12	12	15	laser modulation output inverted
LA	13	13	16	laser modulation output
GND	14	14	17	ground
BIAS	15	15	18	laser bias current output
GND	16	16	19	ground
GND	17	17	20	ground
GND	–	–	21	ground
ALARMHI	18	–	22	maximum bias current alarm reference level input
V _{CC(R)}	–	18	23	supply voltage (red domain); note 3
V _{CC(R)}	19	–	–	supply voltage (red domain); note 3
DLOOP	–	19	24	loop mode data input
V _{CC(R)}	20	–	–	supply voltage (red domain); note 3
DLOOPQ	–	20	25	loop mode data input inverted
V _{CC(R)}	–	–	26	supply voltage (red domain); note 3
ALARMLO	21	–	27	minimum bias current alarm reference level input
V _{CC(R)}	–	21	–	supply voltage (red domain); note 3
ONE	22	22	28	optical 1 reference level input
ZERO	23	23	29	optical 0 reference level input
GND	24	24	30	ground
GND	25	25	31	ground
ALARM	26	–	32	alarm output
ENL	–	26	33	loop mode enable input

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SYMBOL	PIN		PAD	DESCRIPTION
	TZA3041AHL	TZA3041BHL	TZA3041U	
V _{CC(R)}	27	27	34	supply voltage (red domain); note 3
DIN	28	28	35	data input
DINQ	29	29	36	data input inverted
V _{CC(R)}	30	30	37	supply voltage (red domain); note 3
ALS	31	31	38	automatic laser shutdown input
GND	32	32	39	ground
GND	–	–	40	ground

Notes

1. Supply voltage for the Monitor PhotoDiode (MPD) input current.
2. Supply voltage for the laser modulation outputs (LA, LAQ).
3. Supply voltage for the data inputs (DIN, DINQ), optical 1 and 0 reference level inputs (ONE, ZERO), and the bias current alarm reference level inputs (ALARMHI, ALARMLO).

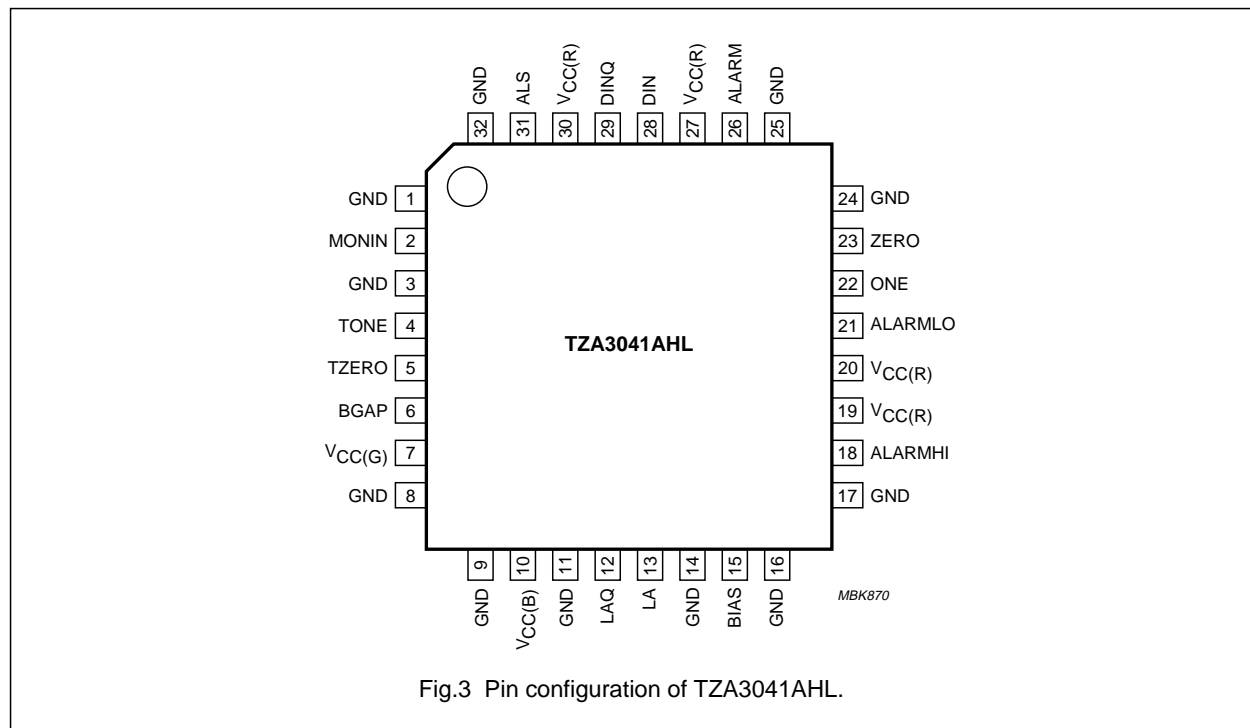


Fig.3 Pin configuration of TZA3041AHL.

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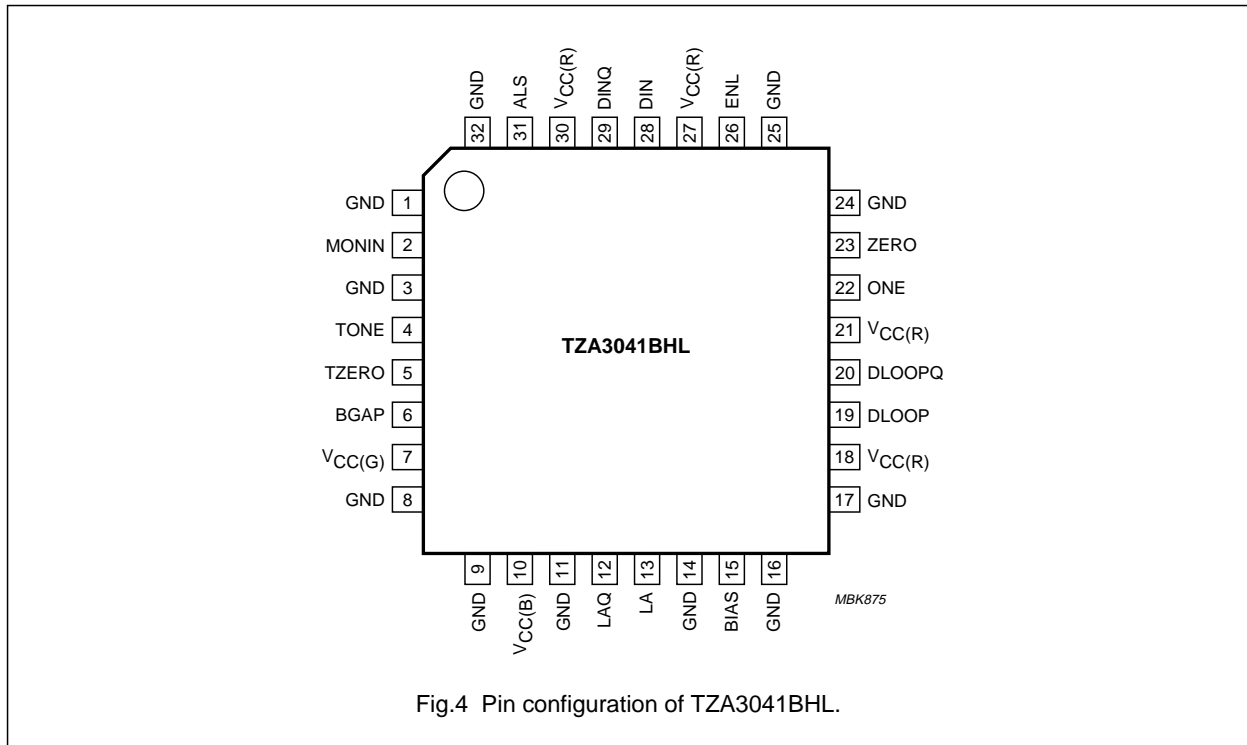


Fig.4 Pin configuration of TZA3041BHL.

FUNCTIONAL DESCRIPTION

The TZA3041AHL, TZA3041BHL and TZA3041U laser drivers accept a 1.2 Gbits/s Non-Return to Zero (NRZ) input data stream, and generate an output signal with sufficient current to drive a solid state Fabry Perot (FP) or Distributed FeedBack (DFB) laser. They also contain dual loop control circuitry for stabilizing the true laser optical power levels representing logic 1 and logic 0.

The input buffers present a high impedance to the data stream on the differential inputs (pins DIN and DINQ); see Fig.5. The input signal can be at a CML level of approximately 200 mV (p-p) below the supply voltage, or at a PECL level up to 800 mV (p-p). The inputs can be configured to accept CML signals by connecting pins DIN and DINQ to $V_{CC(R)}$ via external 50 Ω pull-up resistors. If PECL compatibility is required, the usual Thevenin termination can be applied.

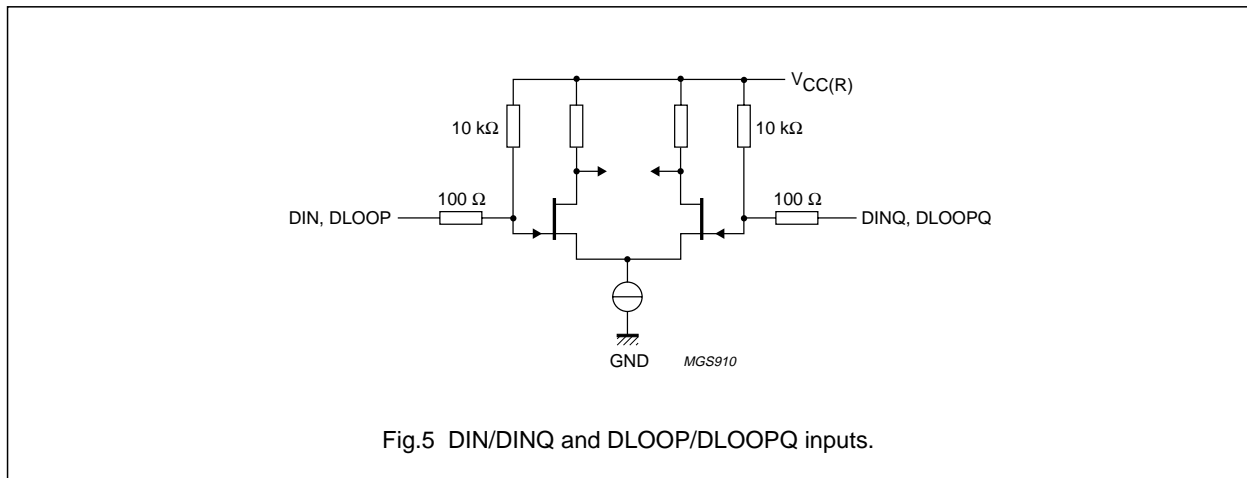


Fig.5 DIN/DINQ and DLOOP/DLOOPQ inputs.

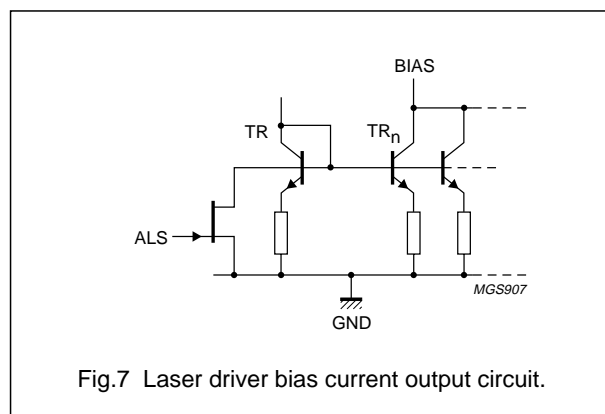
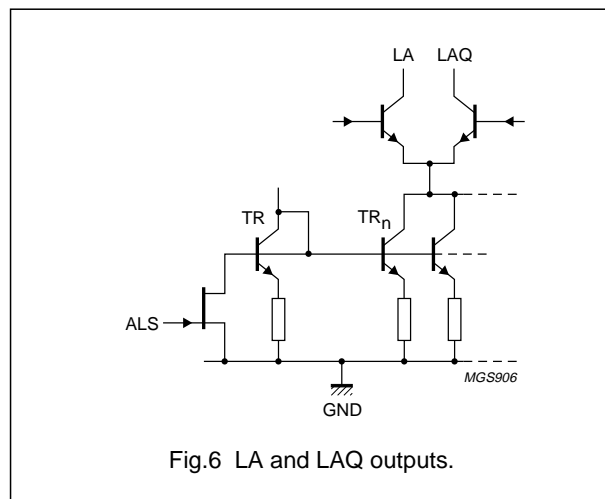
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For ECL signals (negative and referenced to ground), the inputs should be AC-coupled to the signal source.

If AC-coupling is applied, a constant input signal (either LOW or HIGH) will cause the device to be in an undefined state. To avoid this, it is recommended to apply a slight offset to the input stage. The applied offset must be higher than the specified value in Chapter "Characteristics", but much lower than the applied input voltage swing.

The RF path is fully differential and contains a differential preamplifier and a main amplifier. The main amplifier is able to operate at the large peak currents required at the output laser driver stage and is insensitive to supply voltage variations. The output signal from the main amplifier drives a current switch which supplies a guaranteed maximum modulation current of 60 mA to pins LA and LAQ (see Fig.6). The BIAS pin outputs a guaranteed maximum DC bias current of up to 90 mA for adjusting the optical laser output to a level above its light emitting threshold (see Fig.7).

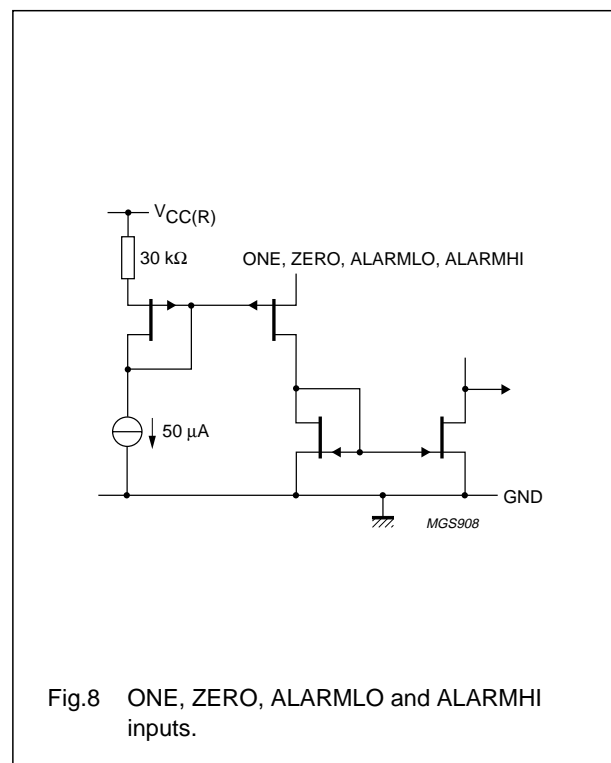


Automatic laser control

A laser with a Monitor PhotoDiode (MPD) is required for the laser control circuit (see application diagrams Figs 18 and 19).

The MPD current is proportional to the laser emission and is applied to pin MONIN. The MPD current range is 100 to 1000 μA (p-p). The input buffer is optimized to cope with an MPD capacitance of up to 50 pF. To prevent the input buffer from oscillating if the MPD capacitance is low, the capacitance should be increased to the minimum value specified in Chapter "Characteristics", by connecting a capacitor between pin MONIN and $V_{CC(G)}$.

DC reference currents are applied to pins ONE and ZERO to set the MPD reference levels for laser HIGH and laser LOW respectively. This is adequately achieved by using resistors to connect $V_{CC(R)}$ to pins ONE and ZERO (see Fig.8), however, current DACs can also be used. The voltages on pins ONE and ZERO are held at a constant level of 1.5 V below $V_{CC(R)}$. The reference current applied to pin ONE is internally multiplied by 16 and the reference current flowing into pin ZERO is internally multiplied by 4. The accuracy of the $V_{CC(R)} - 1.5$ V voltage at pins ONE and ZERO is described in Section "Accuracy of voltage on inputs: ONE, ZERO, ALARMLO, ALARMHI".



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The reference current and the resistor for the optical 1 modulation current control loop is calculated using the following formulae:

$$I_{\text{ref(ONE)}} = \frac{1}{16} \times I_{\text{MPD(ONE)}} \quad [\text{A}] \quad (1)$$

$$R_{\text{ONE}} = \frac{1.5}{I_{\text{ONE}}} = \frac{24}{I_{\text{MPD(ONE)}}} \quad [\Omega] \quad (2)$$

The reference current and resistor for the optical 0 bias current control loop is calculated using the following formulae:

$$I_{\text{ref(ZERO)}} = \frac{1}{4} \times I_{\text{MPD(ZERO)}} \quad [\text{A}] \quad (3)$$

$$R_{\text{ZERO}} = \frac{1.5}{I_{\text{ZERO}}} = \frac{6}{I_{\text{MPD(ZERO)}}} \quad [\Omega] \quad (4)$$

In these formulae, $I_{\text{MPD(ONE)}}$ and $I_{\text{MPD(ZERO)}}$ represent the MPD current during an optical 1 and an optical 0 period, respectively.

EXAMPLE

A laser operates at optical output power levels of 0.3 mW for laser HIGH and 0.03 mW for laser LOW (extinction ratio of 10 dB). Suppose the corresponding MPD currents for this particular laser are 260 and 30 μA , respectively.

In this example, the reference current flowing into pin ONE is:

$$I_{\text{ref(ONE)}} = \frac{1}{16} \times 260 \times 10^{-6} = 16.25 \mu\text{A}$$

This current can be set using a current source or simply by a resistor of the appropriate value connected between pin ONE and $V_{\text{CC(R)}}$.

In this example, the resistor is:

$$R_{\text{ONE}} = \frac{1.5}{16.25 \times 10^{-6}} = 92.3 \text{ k}\Omega$$

In this example, the reference current at pin ZERO is:

$$I_{\text{ref(ZERO)}} = \frac{1}{4} \times 30 \times 10^{-6} = 7.5 \mu\text{A}$$

and can be set using a resistor:

$$R_{\text{ZERO}} = \frac{1.5}{7.5 \times 10^{-6}} = 200 \text{ k}\Omega$$

It should be noted that the MPD current is stabilized rather than the actual laser optical output power. Any deviations between optical output power and MPD current, known as 'tracking errors', cannot be corrected.

Designing the modulation and bias current control loop

The optical 1 and 0 current control loop time constants are determined by on-chip capacitances. If the resulting time constants are found to be too small in a specific application, they can be increased by connecting a capacitor between pins TZERO and TONE.

The optical 1 modulation current control loop time constant (τ) and bandwidth (B) can be estimated using the following formulae:

$$\tau_{\text{ONE}} = (40 \times 10^{-12} + C_{\text{TONE}}) \times \frac{80 \times 10^3}{\eta_{\text{LASER}}} \quad [\text{s}] \quad (5)$$

$$B_{\text{ONE}} = \frac{1}{2\pi \times \tau_{\text{ONE}}} \quad [\text{Hz}] \quad (6)$$

$$B_{\text{ONE}} = \frac{\eta_{\text{LASER}}}{2\pi \times (40 \times 10^{-12} + C_{\text{TONE}}) \times 80 \times 10^3} \quad [\text{Hz}]$$

The optical 0 bias current control loop time constant and bandwidth can be estimated using the following formulae:

$$\tau_{\text{ZERO}} = (40 \times 10^{-12} + C_{\text{TZERO}}) \times \frac{50 \times 10^3}{\eta_{\text{LASER}}} \quad [\text{s}] \quad (7)$$

$$B_{\text{ZERO}} = \frac{1}{2\pi \times \tau_{\text{ZERO}}} \quad [\text{Hz}] \quad (8)$$

$$B_{\text{ZERO}} = \frac{\eta_{\text{LASER}}}{2\pi \times (40 \times 10^{-12} + C_{\text{TZERO}}) \times 50 \times 10^3} \quad [\text{Hz}]$$

The term η_{LASER} (dimensionless) in the above formulae is the product of the following two terms:

- η_{EO} is the electro-optical efficiency which accounts for the steepness of the laser slope characteristic. It defines the rate at which the optical output power increases with modulation current, and is measured in W/A.
- R is the MPD responsivity. It determines the amount of MPD current for a given value of optical output power, and is measured in A/W.

EXAMPLE

A laser with an MPD has the following specifications: $P_{\text{O}} = 1 \text{ mW}$, $I_{\text{th}} = 25 \text{ mA}$, $\eta_{\text{EO}} = 30 \text{ mW/A}$, $R = 500 \text{ mA/W}$. The term I_{th} is the required threshold current to switch on the laser. If the laser operates just above the threshold level, it may be assumed that η_{EO} near the optical 0 level is 50% of η_{EO} near the optical 1 level, due to the slope decreasing near the threshold level.

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In this example, the resulting bandwidth for the optical 1 modulation current control loop, without an external capacitor, is:

$$B_{\text{ONE}} = \frac{30 \times 10^{-3} \times 500 \times 10^{-3}}{2\pi \times 40 \times 10^{-12} \times 80 \times 10^3} \approx 750 \text{ Hz}$$

The resulting bandwidth for the optical 0 bias current control loop, without an external capacitor, is:

$$B_{\text{ZERO}} = \frac{0.5 \times 30 \times 10^{-3} \times 500 \times 10^{-3}}{2\pi \times 40 \times 10^{-12} \times 50 \times 10^3} \approx 600 \text{ Hz}$$

It is not necessary to add additional capacitance with this type of laser.

Control loop data pattern and bit rate dependency

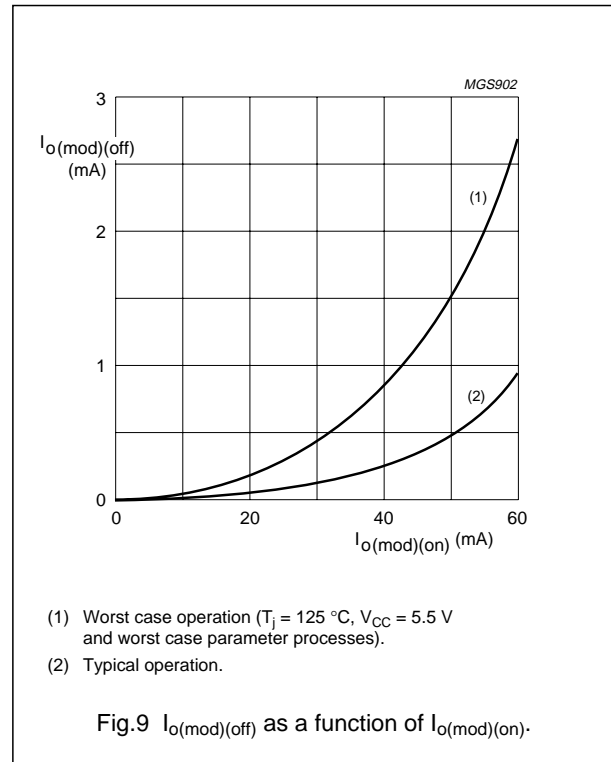
The constants in equations (1) and (3) are valid when the data pattern frequently contains a sufficient number of 'constant zeroes' and 'constant ones'. A single control loop time period (τ_{ONE} and τ_{ZERO}) must contain ones and zeros for at least approximately 6 ns. When using the IC in 1.2 Gbits/s applications, the optical extinction ratio will be slightly higher when compared with slower line rates. Therefore, it is important to use the actual data patterns and bit rate of the final application circuit for adjusting the optical levels.

The laser driver peak detectors are able to track MPD output current overshoot and undershoot conditions. Unfortunately, these conditions affect the ability of the IC to correctly interpret the high and low level MPD current. In particular, the occurrence of undershoot can have a markedly adverse effect on the interpretation of the low level MPD current.

Additional bias by modulation 'off' current

Although during operation, the full modulation current switches between outputs LA and LAQ, a small amount of modulation current continues to flow through the inactive pin.

For example, when the laser, whose cathode is connected to LA, is in the 'dark' part of its operating cycle (logic 0), some of the modulation 'off' current flows through LA while most of the current flows through LAQ. This value $I_{\text{o(mod)}(\text{off})}$ is effectively added to the bias current and is subtracted from the modulation current. Fortunately, the value correlates closely with the magnitude of the modulation current. Therefore, applications requiring low bias and low modulation are less affected. Figure 9 shows the modulation 'off' current as a function of the modulation 'on' current.



Monitoring the bias and modulation current

Although not recommended, the bias and modulation currents generated by the laser driver can be monitored by measuring the voltages on pins TZERO and TONE, respectively (see Fig.10). The relationship between these voltages and the corresponding currents are given as transconductance values and are specified in Chapter "Characteristics". The voltages on pins TZERO and TONE range from 1.4 to 3.4 V. Any connection to these pins should have a very high impedance value. It is mandatory to use a CMOS buffer or an amplifier with an input impedance higher than 100 G Ω and with an extremely low input leakage current (pA).

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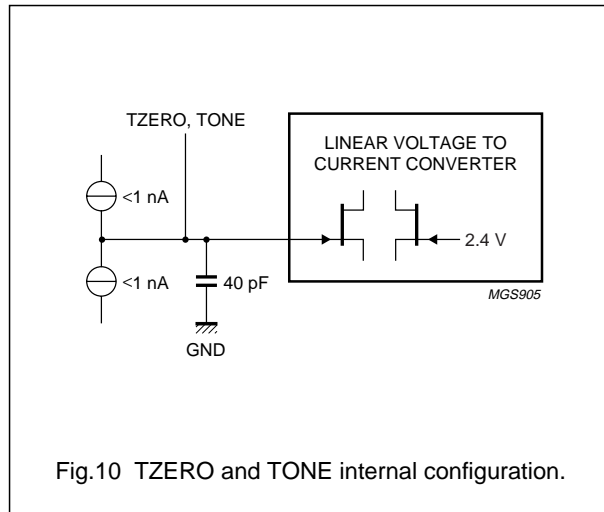


Fig.10 TZERO and TONE internal configuration.

Manual laser override

The automatic laser control function can be overridden by connecting voltage sources to pins TZERO and TONE to take direct control of the current sources for bias and modulation respectively. The control voltages should range from 1.4 to 3.4 V to swing the modulation current over the range 1 to 60 mA and the bias current over the range 1 to 90 mA. These current ranges are guaranteed.

Due to the tolerance range in the manufacturing process, some devices may have higher current values than those specified, as shown in Figs 12 and 13. Both figures show that temperature changes cause a slight tilting of the linear characteristic around an input voltage of 2.4 V.

Consequently, the manually controlled current level is most insensitive to temperature variations at around this value. Bias and modulation currents in excess of the specified range are not supported and should be avoided.

Currents into or out of pins TZERO and TONE in excess of $10 \mu\text{A}$ must be avoided to prevent damage to the circuit.

Automatic laser shut-down and laser slow start

The laser modulation and bias currents can be rapidly switched off when a HIGH level (CMOS) is applied to pin ALS. This function allows the circuit to be shut-down in the event of an optical system malfunction. A $25 \text{ k}\Omega$ pull-down resistor defaults pin ALS to the non active state (see Fig.11).

When a LOW level is applied to pin ALS, the modulation and bias currents slowly increase to the desired values at the typical time constants of τ_{TONE} and τ_{TZERO} , respectively. This can be used to slow-start the laser.

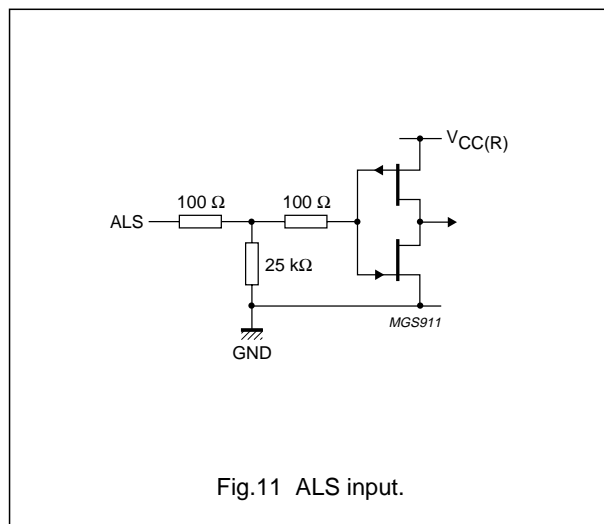
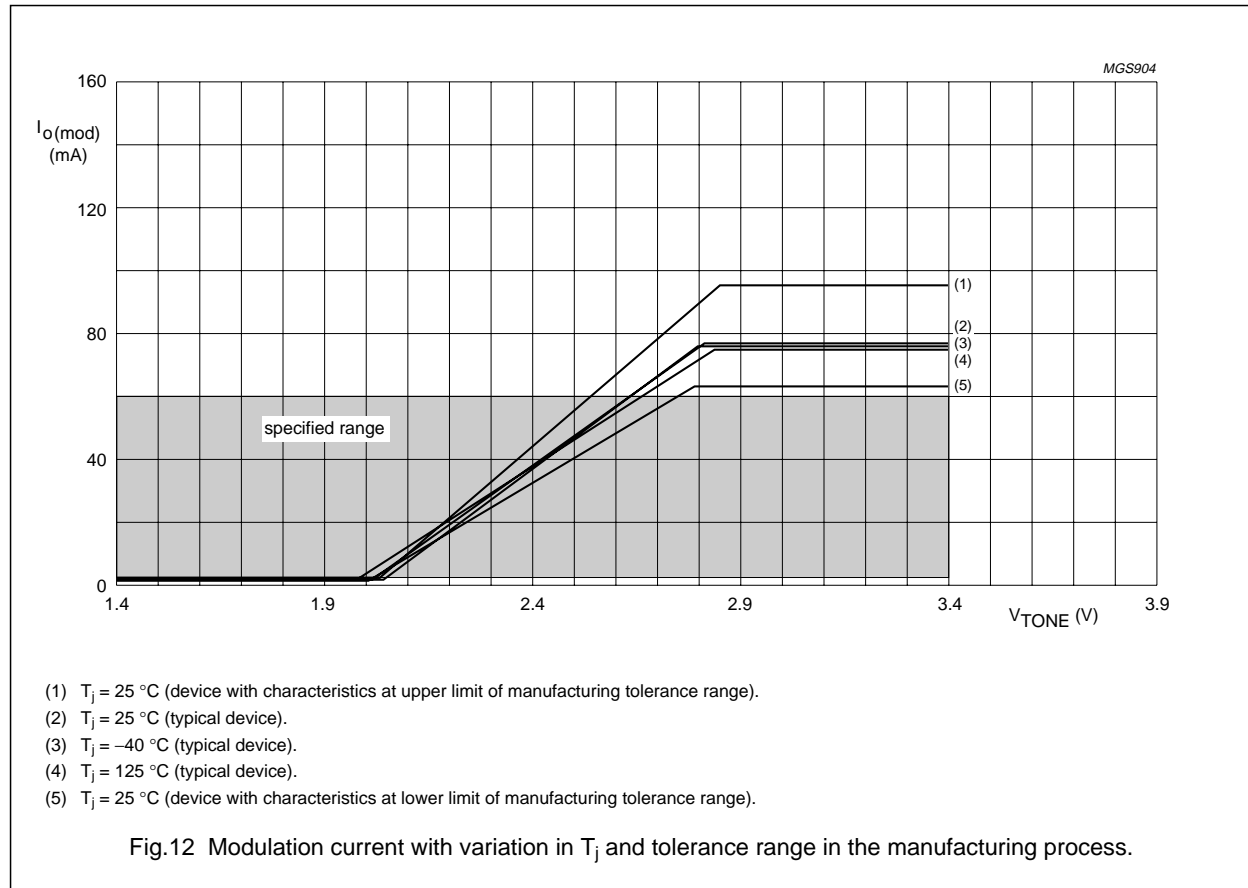
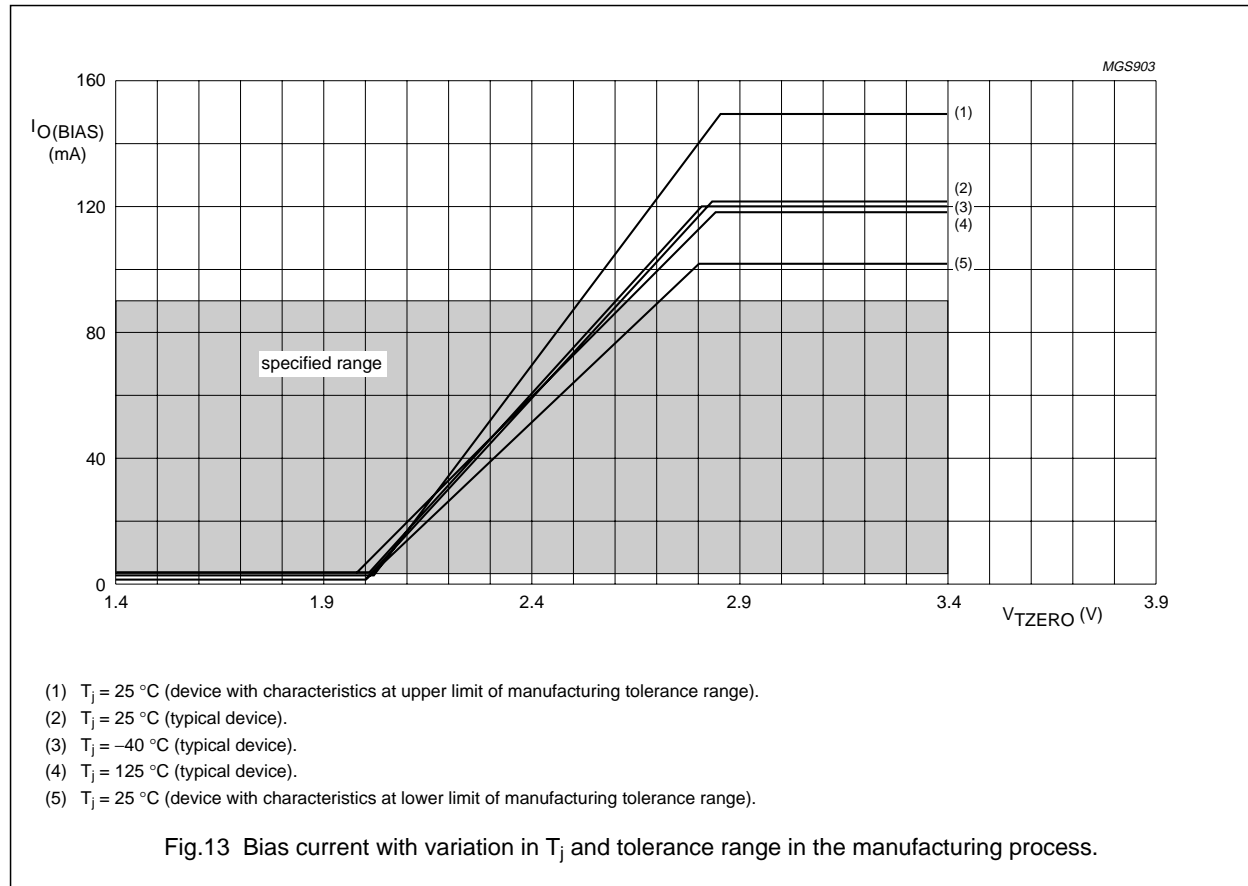


Fig.11 ALS input.

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Bias alarm for TZA3041AHL

The bias current alarm circuit detects whenever the bias current is outside a predefined range, and generates a flag. This feature can detect excessive bias current due to laser ageing or laser malfunctioning. The current applied to pin ALARMHI should be the maximum permitted bias current value attenuated by a ratio of 1:1500. The current applied to pin ALARMLO should be the minimum permitted bias current value attenuated by a ratio of 1:300.

Like the reference currents for the laser current control loop, the alarm reference currents can be set by connecting external resistors between $V_{CC(R)}$ and pins ALARMHI and ALARMLO (see Fig.8). The resistor values can be calculated using the following formulae:

$$R_{ALARMHI} = \frac{1.5 \times 1500}{I_{O(BIAS)(max)}} \quad [\Omega] \quad (9)$$

$$R_{ALARMLO} = \frac{1.5 \times 300}{I_{O(BIAS)(min)}} \quad [\Omega] \quad (10)$$

Example: The following reference currents are required to limit the bias current range from 6 to 90 mA:

$$I_{ALARMLO} = \frac{6 \times 10^{-3}}{300} = 20 \mu\text{A} \text{ and}$$

$$I_{ALARMHI} = \frac{90 \times 10^{-3}}{1500} = 60 \mu\text{A}$$

The corresponding resistor values are:

$$R_{ALARMHI} = \frac{1.5 \times 1500}{90 \times 10^{-3}} = 25 \text{ k}\Omega \text{ and}$$

$$R_{ALARMLO} = \frac{1.5 \times 300}{6 \times 10^{-3}} = 75 \text{ k}\Omega$$

If the alarm condition is true, the voltage on pin ALARM (see Fig.14) goes to a HIGH level (CMOS). This signal could be used, for example, to drive pin ALS to disable the laser driver; the signal to pin ALS has to be latched to prevent oscillation.

A hysteresis of approximately 10% is applied to both alarm functions. The attenuation ratios of 1:300 and 1:1500 are valid if the bias current rises above the reference current levels. If the bias current decreases, the ratios are 10% lower.

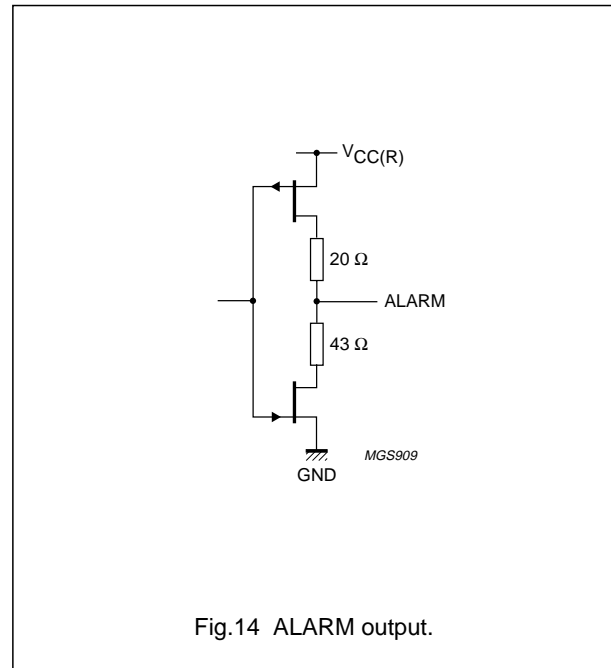


Fig.14 ALARM output.

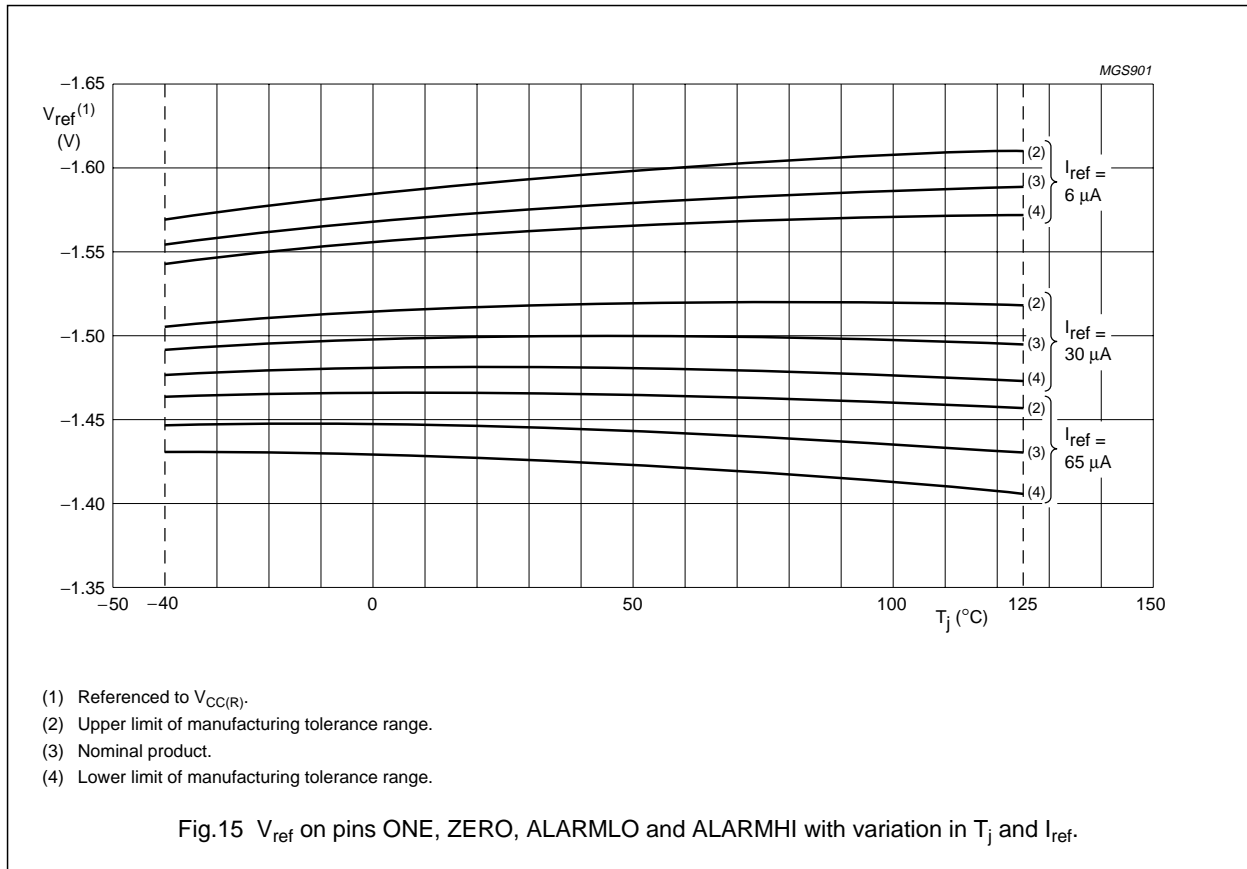
Accuracy of voltage on inputs: ONE, ZERO, ALARMLO, ALARMHI

It is important to consider the accuracy of the 1.5 V level with respect to $V_{CC(R)}$ on pins ONE and ZERO if resistors are used to set the reference currents. Although this value is independent of $V_{CC(R)}$, deviations from 1.5 V can be caused by:

- Input current: At $T_j = 25^\circ\text{C}$, the voltage between pin and V_{CC} varies from 1.58 V at an input current of 6 μA , down to 1.45 V at 65 μA and 1.41 V at 100 μA . The range between 65 μA and 100 μA is only specified for ALARMLO. In the application, the input current is virtually fixed, so this variation has little effect.
- Variation in batch and individual device characteristics, not exceeding $\pm 2\%$ from the nominal product: This variation can be compensated for where devices in the application are individually trimmed.
- Temperature: The variation in T_j is shown in Fig.15. At 30 μA (middle of the specified range) the total variation in T_j is $< 1\%$, at 65 μA it is $< 2\%$ and at 6 μA it is $< 3\%$.

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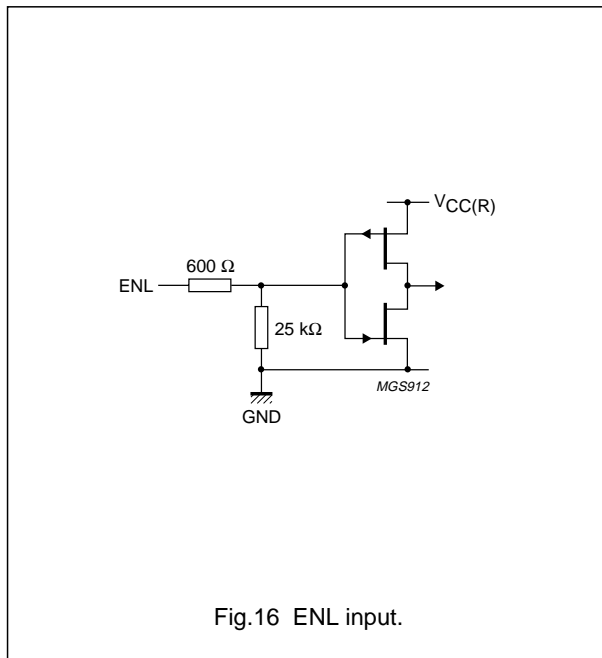
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Loop mode for TZA3041BHL

The loop mode allows the total system application to be tested. It allows for uninhibited optical transmission through the fibre front-end (from the MPD through the transimpedance stage and the data and clock recovery unit, to the laser driver and via the laser back to the fibre). Note that the optical receiver used in conjunction with the TZA3041BHL must have a loop mode output in order to complete the test loop.

The loop mode is selected by a HIGH level on pin ENL. By default, pin ENL is pulled to a LOW level by a 25 k Ω pull-down resistor (see Fig.16).



Power supply connections

Refer to application diagrams Figs 18 and 19. Three separate supply domains (labelled $V_{CC(G)}$, $V_{CC(B)}$, and $V_{CC(R)}$) provide isolation between the MPD current input, the high-current outputs, and the PECL or CML inputs. Each supply domain should be connected to a central V_{CC} via separate filters as shown in Figs 18 and 19. **All supply pins must be connected.** The voltage supply levels should be equal to, and in accordance with, the values specified in Chapter "Characteristics".

To maximize power supply isolation, the cathode of the MPD should be connected to $V_{CC(G)}$ and the anode of the laser diode should be connected to $V_{CC(B)}$. It is recommended that the laser diode anode is also connected to a separate decoupling capacitor C9.

Generally, the inverted laser modulation output (pin LAQ) is not used. To correctly balance the output stage, an equalization network (Z1) with an impedance comparable to the laser diode is connected between pin LAQ and $V_{CC(B)}$.

All external components should be surface mounted devices, preferably of size 0603 or smaller. The components must be mounted as close to the IC as possible.

It is especially recommended to mount the following components very close to the IC:

- Power supply decoupling capacitors C2, C3 and C4
- Input matching network on pins DIN, DINQ, DLOOP and DLOOPQ
- Capacitor C5 on pin MONIN
- Output matching network Z1 at the unused output
- The laser.

Bare die ground

In addition to the separate V_{CC} domains, the bare die contains three corresponding ground (GND) domains. Isolation between the GND domains is limited due to the finite substrate conductance.

Mount the die preferably on a large and highly conductive grounded die pad. **All GND pads must be bonded to the die pad.** The external ground is thus ideally combined with the die ground to avoid ground bounce problems.

Layout recommendations

Layout recommendations for the TZA3041AHL and TZA3041BHL can be found in application note "AN98090 Fiber optic transceiverboard STM1/4/8, OC3, 12, 24, FC/GE".

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TZA3041U**LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V_{CC}	supply voltage	-0.5	+6	V
V_n	DC voltage on			
	pin MONIN	1.3	$V_{CC} + 0.5$	V
	pins TONE and TZERO	-0.5	$V_{CC} + 0.5$	V
	pin BGAP	-0.5	+3.2	V
	pin BIAS	-0.5	$V_{CC} + 0.5$	V
	pins LA and LAQ	1.3	$V_{CC} + 0.5$	V
	pin ALS	-0.5	$V_{CC} + 0.5$	V
	pins ONE and ZERO	-0.5	$V_{CC} + 0.5$	V
	pins DIN and DINQ	-0.5	$V_{CC} + 0.5$	V
	pin ALARM (TZA3041AHL)	-0.5	$V_{CC} + 0.5$	V
	pins ALARMHI and ALARMLO (TZA3041AHL)	-0.5	$V_{CC} + 0.5$	V
	pins DLOOP and DLOOPQ (TZA3041BHL)	-0.5	$V_{CC} + 0.5$	V
	pin ENL (TZA3041BHL)	-0.5	$V_{CC} + 0.5$	V
I_n	DC current on			
	pin MONIN	-0.5	+2.5	mA
	pins TONE and TZERO	-0.5	+0.5	mA
	pin BGAP	-2.0	+2.5	mA
	pin BIAS	-0.5	+200	mA
	pins LA and LAQ	-0.5	+100	mA
	pin ALS	-0.5	+0.5	mA
	pins ONE and ZERO	-0.5	+0.5	mA
	pins DIN and DINQ	-0.5	+0.5	mA
	pin ALARM (TZA3041AHL)	-0.5	+10	mA
	pins ALARMHI and ALARMLO (TZA3041AHL)	-0.5	+0.5	mA
	pins DLOOP and DLOOPQ (TZA3041BHL)	-0.5	+0.5	mA
	pin ENL (TZA3041BHL)	-0.5	+0.5	mA
T_{amb}	ambient temperature	-40	+85	°C
T_j	junction temperature	-40	+125	°C
T_{stg}	storage temperature	-65	+150	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
$R_{th(j-s)}$	thermal resistance from junction to solder point	15	K/W
$R_{th(j-c)}$	thermal resistance from junction to case	23	K/W

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$V_{CC} = 4.5$ to 5.5 V; $T_{amb} = -40$ to $+85$ °C; all voltages measured with respect to GND.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Supplies						
V_{CC}	supply voltage		4.5	5.0	5.5	V
$I_{CC(R)}$	supply current (R)		–	4	10	mA
$I_{CC(G)}$	supply current (G)		12	18	26	mA
$I_{CC(B)}$	supply current (B)	ALS LOW; note 1	20	41	65	mA
		ALS HIGH	–	3	5	mA
$I_{CC(tot)}$	total supply current	ALS LOW; note 1	32	63	101	mA
		ALS HIGH	12	25	41	mA
P_{tot}	total power dissipation	ALS LOW; note 2	145	430	925	mW
		ALS HIGH; note 2	50	125	225	mW
Data inputs: pins DIN and DINQ (and pins DLOOP and DLOOPQ on TZA3041BHL); see Fig.17						
$V_{i(p-p)}$	input voltage (peak-to-peak value)	single-ended	100	250	800	mV
V_{IO}	input offset voltage		–25	–	+25	mV
$V_{I(min)}$	minimum input voltage		$V_{CC(R)} - 2$	–	–	V
$V_{I(max)}$	maximum input voltage		–	–	$V_{CC(R)} + 0.25$	V
Z_i	input impedance	for low frequencies; single-ended	7	10	13	k Ω
CMOS inputs: pin ALS (and pin ENL on TZA3041BHL)						
V_{IL}	LOW-level input voltage		–	–	2	V
V_{IH}	HIGH-level input voltage		3	–	–	V
$R_{pd(ALS)}$	internal pull-down resistance on pin ALS		21	25.5	30	k Ω
$R_{pd(ENL)}$	internal pull-down resistance on pin ENL		15	25	35	k Ω
CMOS output: pin ALARM (on TZA3041AHL)						
V_{OL}	LOW-level output voltage	$I_{OH} = -200 \mu A$	0	–	0.2	V
V_{OH}	HIGH-level output voltage	$I_{OH} = 200 \mu A$	$V_{CC} - 0.2$	–	V_{CC}	V
Monitor photodiode input: pin MONIN						
V_I	DC input voltage		1.2	1.8	2.4	V
I_{MPD}	monitor photodiode current	laser optical 0	24	–	260	μA
		laser optical 1	96	–	1040	μA
C_{MPD}	monitor photodiode capacitance	note 3	30	–	50	pF

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Control loop reference current inputs: pins ONE and ZERO						
$I_{\text{ref(ONE)}}$	reference current on pin ONE	note 4	6	–	65	μA
$V_{\text{ref(ONE)}}$	reference voltage on pin ONE	referenced to $V_{\text{CC(R)}}$; note 5	–	–1.5	–	V
$\alpha_{\text{(ONE)}}$	attenuation ratio of $I_{\text{ref(ONE)}}$ to $I_{\text{MPD(ONE)}}$	note 6	–	16	–	–
$I_{\text{ref(ZERO)}}$	reference current on pin ZERO	note 4	6	–	65	μA
$V_{\text{ref(ZERO)}}$	reference voltage on pin ZERO	referenced to $V_{\text{CC(R)}}$; note 5	–	–1.5	–	V
$\alpha_{\text{(ZERO)}}$	attenuation ratio of $I_{\text{ref(ZERO)}}$ to $I_{\text{MPD(ZERO)}}$	note 6	–	4	–	–
Control loop time constants: pins TONE and TZERO						
V_{TONE}	voltage on pin TONE	floating output	1.4	–	3.4	V
$g_{\text{m(TONE)}}$	transconductance of pin TONE	note 7	60	95	130	mA/V
V_{TZERO}	voltage on pin TZERO	floating output	1.4	–	3.4	V
$g_{\text{m(TZERO)}}$	transconductance of pin TZERO	note 8	100	145	190	mA/V
Laser modulation current outputs: pins LA and LAQ						
$I_{\text{o(mod)(on)}}$	modulation output current (active pin)	note 9	2.5	–	60	mA
$I_{\text{o(mod)(off)}}$	modulation output current (inactive pin)	$I_{\text{o(mod)(on)} = 30\text{mA}}$	–	–	0.5	mA
		$I_{\text{o(mod)(on)} = 60\text{mA}}$	–	–	2.8	mA
$I_{\text{o(mod)(ALS)}}$	output current during laser shutdown		–	–	10	μA
V_{O}	output voltage		2	–	5	V
t_{r}	current rise time	note 10	–	120	200	ps
t_{f}	current fall time	note 10	–	120	200	ps
$J_{\text{o(p-p)}}$	intrinsic electrical output jitter (peak-to-peak value)	note 11	–	–	50	mUI
Laser bias current output: pin BIAS						
$I_{\text{O(BIAS)}}$	bias output current	note 12	2.8	–	90	mA
$I_{\text{O(BIAS)(ALS)}}$	output current during laser shutdown		–	–	10	μA
$t_{\text{res(off)}}$	response time after laser shutdown	$I_{\text{O(BIAS)}} = 90\text{ mA}$; note 13	–	–	1	μs
$V_{\text{O(BIAS)}}$	bias output voltage		1	–	5	V

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Alarm reference current inputs: pins ALARMHI and ALARMLO (TZA3041AHL)						
$I_{\text{ref(ALARMLO)}}$	reference current on pin ALARMLO	note 14	6	–	100	μA
$V_{\text{ref(ALARMLO)}}$	reference voltage on pin ALARMLO	referenced to $V_{\text{CC(R)}}$	–	–1.5	–	V
$\alpha_{\text{(ALARMLO)}}$	attenuation ratio of $I_{\text{ref(ALARMLO)}}$ to $I_{\text{O(BIAS)(min)}}$	note 15	200	315	400	
$I_{\text{O(BIAS)(min)(hys)}}$	minimum bias current detection hysteresis		7.5	10	15	%
$I_{\text{ref(ALARMHI)}}$	reference current on pin ALARMHI	note 14	6	–	65	μA
$V_{\text{ref(ALARMHI)}}$	reference voltage on pin ALARMHI	referenced to $V_{\text{CC(R)}}$	–	–1.5	–	V
$\alpha_{\text{(ALARMHI)}}$	attenuation ratio of $I_{\text{ref(ALARMHI)}}$ to $I_{\text{O(BIAS)(max)}}$	note 15	1300	1600	1800	
$I_{\text{O(BIAS)(max)(hys)}}$	maximum bias current detection hysteresis		7.5	10	15	%
Reference voltage output: pin BGAP						
V_{O}	output voltage		1.165	1.20	1.235	μA

Notes

1. Supply current:

- The values do not include the modulation and bias currents through pins LA, LAQ and BIAS.
- Minimum value refers to $V_{\text{TONE}} = 1.4 \text{ V}$ at $I_{\text{O(mod)(min)}}$ and $V_{\text{TZERO}} = 1.4 \text{ V}$ at $I_{\text{O(BIAS)(min)}}$.
- Maximum value refers to $V_{\text{TONE}} = 3.4 \text{ V}$ at $I_{\text{O(mod)(max)}}$ and $V_{\text{TZERO}} = 3.4 \text{ V}$ at $I_{\text{O(BIAS)(max)}}$.
- A first order estimate of the typical value of $I_{\text{CC(tot)}}$ as a function of T_{j} , $I_{\text{O(mod)}}$, and $I_{\text{O(BIAS)}}$ is:

$$I_{\text{CC(tot)}} = 55.6 \text{ mA} + 0.0015 \times I_{\text{O(BIAS)}} [\text{mA}] \times I_{\text{O(mod)(on)}} [\text{mA}] \times \left(1 - \left[0.026 \times \frac{T_{\text{j}} [\text{°C}]}{25} \right] \right)$$

2. Power dissipation:

- The value for P_{tot} includes the modulation and bias currents through pins LA, LAQ and BIAS.
- The minimum value for P_{tot} is the on-chip dissipation when $V_{\text{TONE}} = 1.4 \text{ V}$ at $I_{\text{O(mod)(min)}}$, $V_{\text{LA}} = V_{\text{LAQ}} = 2 \text{ V}$, $V_{\text{TZERO}} = 1.4 \text{ V}$ at $I_{\text{O(BIAS)(min)}}$, $V_{\text{O(BIAS)}} = 1 \text{ V}$, and parameter processes are at a minimum.
- The maximum value for P_{tot} is the on-chip dissipation when $V_{\text{TONE}} = 3.4 \text{ V}$ at $I_{\text{O(mod)(max)}}$, $V_{\text{LA}} = V_{\text{LAQ}} = 2 \text{ V}$, $V_{\text{TZERO}} = 3.4 \text{ V}$ at $I_{\text{O(BIAS)(max)}}$, $V_{\text{O(BIAS)}} = 1 \text{ V}$, and parameter processes are at a maximum.
- $P_{\text{tot}} = I_{\text{CC(tot)}} \times V_{\text{CC}} + I_{\text{O(BIAS)}} \times V_{\text{O(BIAS)}} + I_{\text{LA}} \times V_{\text{LA}}$ with $I_{\text{O(mod)(on)}}$ flowing through pin LA.

3. The minimum value of the capacitance on pin MONIN is required to prevent instability.

4. The reference currents can be set by connecting external resistors between V_{CC} and pins ONE and ZERO (see Section “Automatic laser control”). The corresponding MPD current range for optical 1 is from 96 to 1040 μA . The MPD current range for optical 0 is from 24 to 260 μA .

5. See Section “Accuracy of voltage on inputs: ONE, ZERO, ALARMLO, ALARMHI”.

6. See Section “Automatic laser control”.

7. The specified transconductance is the ratio between the modulation current on pins LA or LAQ and the voltage on pin TONE, under small signal conditions.

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8. The specified transconductance is the ratio between the bias current on pin BIAS and the voltage on pin TZERO, under small signal conditions.
9. These are the guaranteed values; the lowest attainable output current will always be lower than 2.5 mA, and the highest output current will always be higher than 60 mA.
10. The voltage rise and fall times (20% to 80%) can have larger values due to capacitive effects. Specifications are guaranteed by design and characterization. Each device is tested at full operating speed to guarantee RF functionality.
11. Measured according to IEEE 802.3z and ANSI X3.230. The electrically generated (current) jitter is assumed to be less than 50% of the optical output jitter. The specification is guaranteed by design.
12. These are the guaranteed values; the lowest output current will always be less than 2.8 mA and the highest output current will always be more than 90 mA.
13. The response time is defined as the delay between the onset of the ramp on pin ALS (at 10% of the HIGH level) and the extinction of the bias current (at 10% of the original value).
14. The reference currents can be set by connecting a resistor between pin ALARMLO and $V_{CC(R)}$ and between pin ALARMHI and $V_{CC(R)}$; for detailed information, see Section "Bias alarm for TZA3041AHL". The corresponding low-bias threshold range is 1.8 to 19.5 mA. The high-bias threshold range is 9 to 97.5 mA.
15. See Section "Bias alarm for TZA3041AHL".

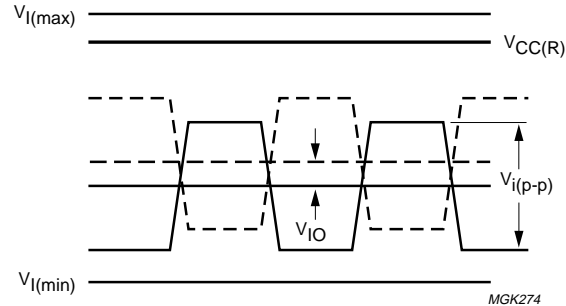


Fig.17 Logic level symbol definitions for data inputs.

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APPLICATION INFORMATION

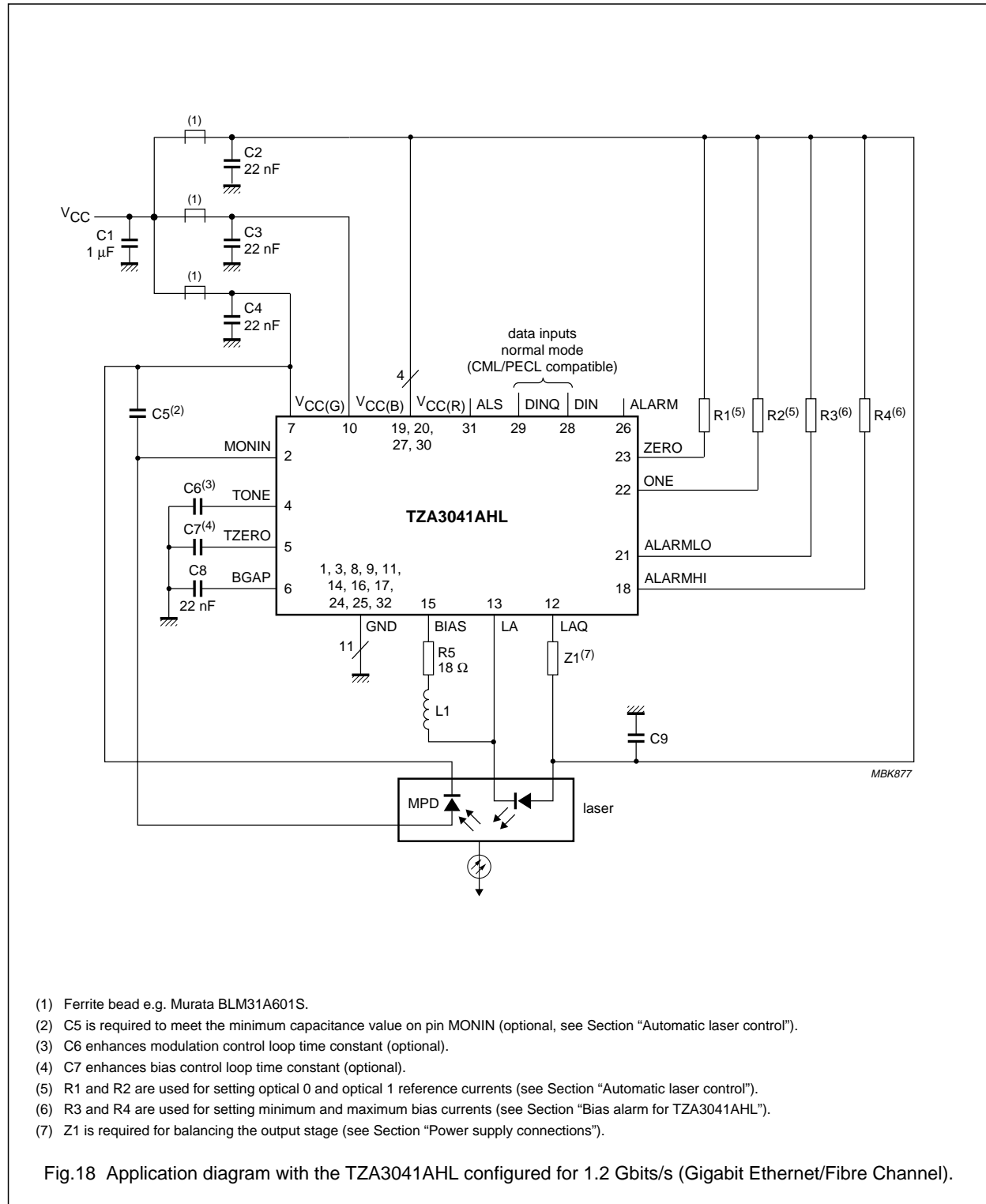
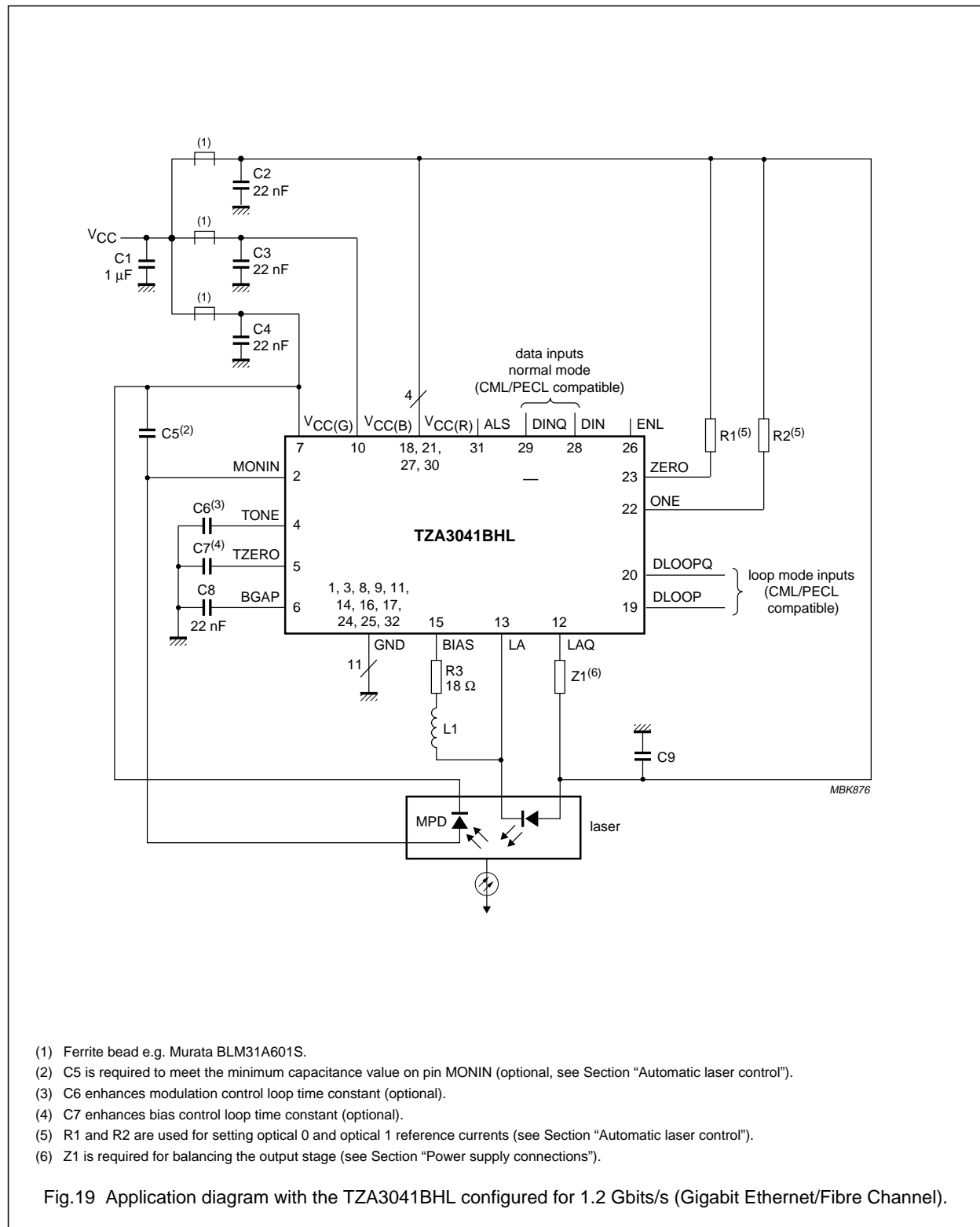


Fig.18 Application diagram with the TZA3041AHL configured for 1.2 Gbits/s (Gigabit Ethernet/Fibre Channel).

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BONDING PAD LOCATIONS

SYMBOL	PAD	COORDINATES ⁽¹⁾	
		x	y
GND	1	-664	-910
MONIN	2	-524	-910
GND	3	-367	-910
IGM	4	-227	-910
TONE	5	-70	-910
TZERO	6	+87	-910
BGAP	7	+244	-910
V _{CC(G)}	8	+384	-910
V _{CC(G)}	9	+524	-910
GND	10	+664	-910
GND	11	+910	-630
V _{CC(B)}	12	+910	-490
V _{CC(B)}	13	+910	-350
GND	14	+910	-210
LAQ	15	+910	-70
LA	16	+910	+70
GND	17	+910	+210
BIAS	18	+910	+350
GND	19	+910	+490
GND	20	+910	+630
GND	21	+681	+910
ALARMHI	22	+541	+910

SYMBOL	PAD	COORDINATES ⁽¹⁾	
		x	y
V _{CC(R)}	23	+384	+910
DLOOP	24	+227	+910
DLOOPQ	25	+87	+910
V _{CC(R)}	26	-70	+910
ALARMLO	27	-210	+910
ONE	28	-367	+910
ZERO	29	-524	+910
GND	30	-681	+910
GND	31	-910	+681
ALARM	32	-910	+541
ENL	33	-910	+384
V _{CC(R)}	34	-910	+227
DIN	35	-910	+70
DINQ	36	-910	-70
V _{CC(R)}	37	-910	-227
ALS	38	-910	-367
GND	39	-910	-551
GND	40	-910	-664

Note

1. All x and y coordinates represent the position of the centre of the pad in μm with respect to the centre of the die (see Fig.20).

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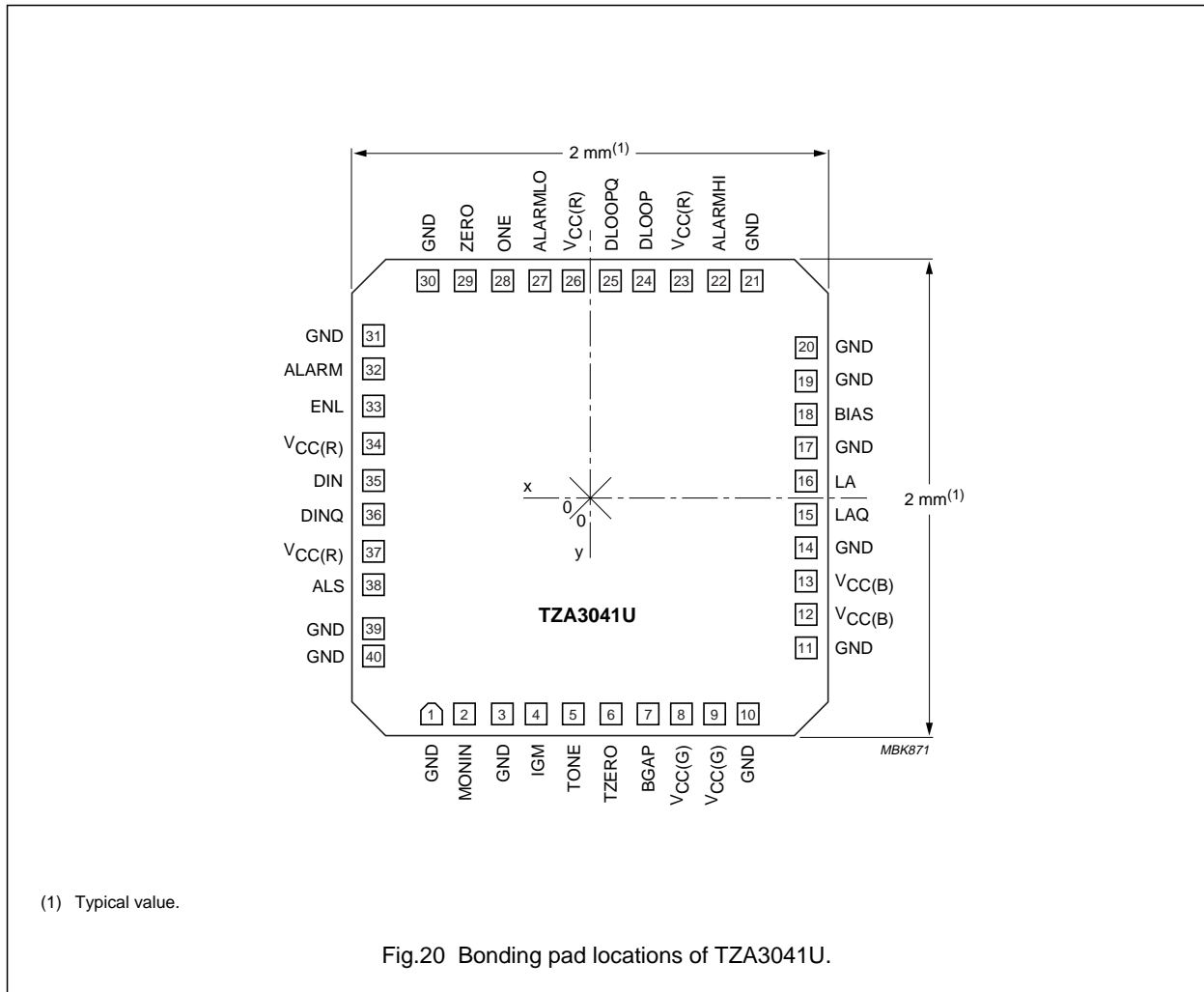


Table 1 Physical characteristics of bare die

PARAMETER	VALUE
Glass passivation	2.1 μm PSG (PhosphoSilicate Glass) on top of 0.7 μm silicon nitride
Bonding pad dimension	minimum dimension of exposed metallization is $90 \times 90 \mu\text{m}$ (pad size = $100 \times 100 \mu\text{m}$)
Metallization	1.2 μm AlCu (1% Cu)
Thickness	380 μm nominal
Size	2.000 \times 2.000 mm (4.000 mm ²)
Backing	silicon; electrically connected to GND potential through substrate contacts
Attach temperature	<430 $^{\circ}\text{C}$; glue is recommended for attaching die
Attach time	<15 s

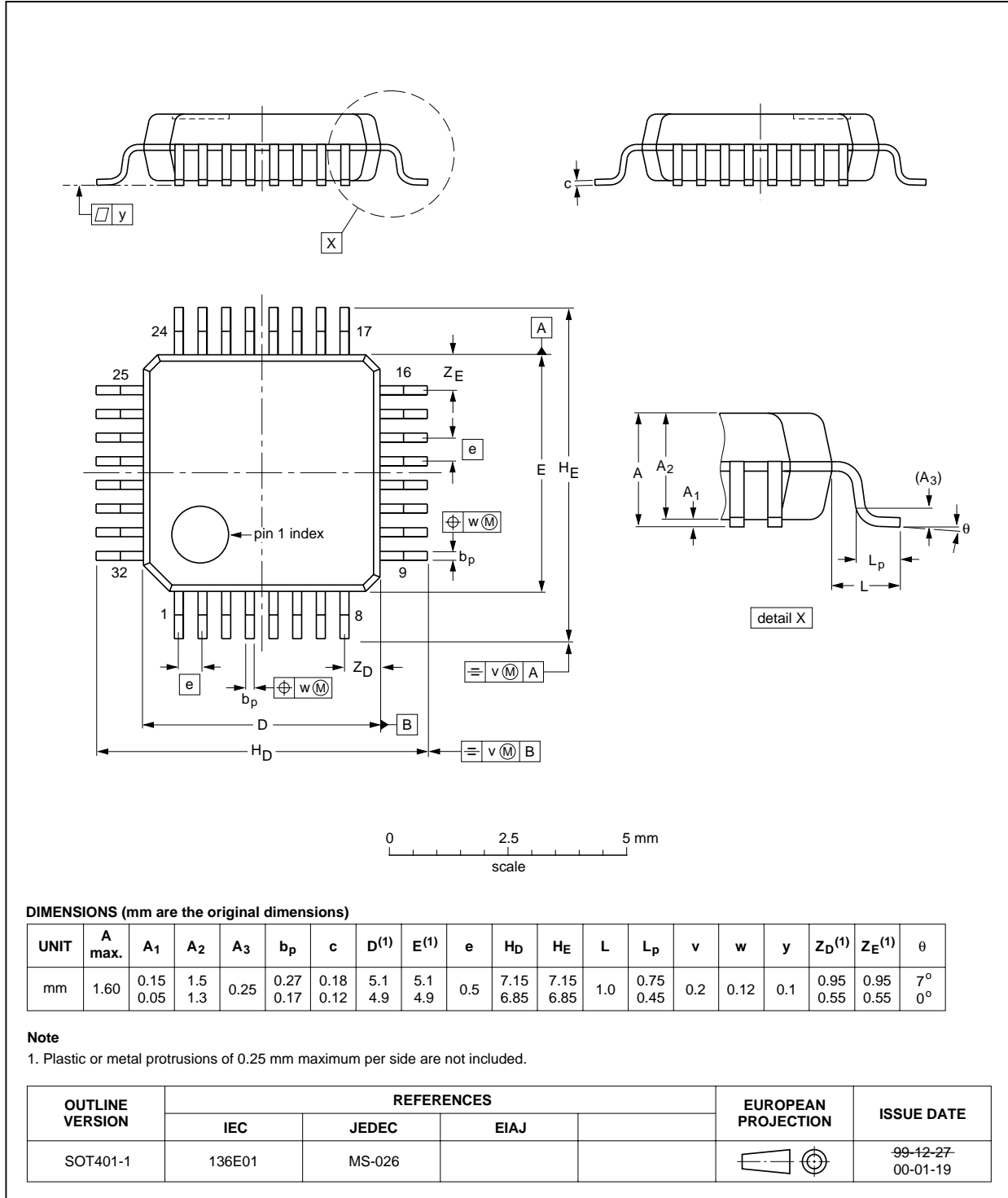
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PACKAGE OUTLINE

LQFP32: plastic low profile quad flat package; 32 leads; body 5 x 5 x 1.4 mm

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SOLDERING

Introduction to soldering surface mount packages

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"Data Handbook IC26; Integrated Circuit Packages"* (document order number 9398 652 90011).

There is no soldering method that is ideal for all surface mount IC packages. Wave soldering can still be used for certain surface mount ICs, but it is not suitable for fine pitch SMDs. In these situations reflow soldering is recommended.

Reflow soldering

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several methods exist for reflowing; for example, convection or convection/infrared heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 100 and 200 seconds depending on heating method.

Typical reflow peak temperatures range from 215 to 250 °C. The top-surface temperature of the packages should preferably be kept below 220 °C for thick/large packages, and below 235 °C for small/thin packages.

Wave soldering

Conventional single wave soldering is not recommended for surface mount devices (SMDs) or printed-circuit boards with a high component density, as solder bridging and non-wetting can present major problems.

To overcome these problems the double-wave soldering method was specifically developed.

If wave soldering is used the following conditions must be observed for optimal results:

- Use a double-wave soldering method comprising a turbulent wave with high upward pressure followed by a smooth laminar wave.
- For packages with leads on two sides and a pitch (e):
 - larger than or equal to 1.27 mm, the footprint longitudinal axis is **preferred** to be parallel to the transport direction of the printed-circuit board;
 - smaller than 1.27 mm, the footprint longitudinal axis **must** be parallel to the transport direction of the printed-circuit board.

The footprint must incorporate solder thieves at the downstream end.

- For packages with leads on four sides, the footprint must be placed at a 45° angle to the transport direction of the printed-circuit board. The footprint must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Typical dwell time is 4 seconds at 250 °C.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

Manual soldering

Fix the component by first soldering two diagonally-opposite end leads. Use a low voltage (24 V or less) soldering iron applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C.

When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 °C.

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Suitability of surface mount IC packages for wave and reflow soldering methods

PACKAGE ⁽¹⁾	SOLDERING METHOD	
	WAVE	REFLOW ⁽²⁾
BGA, LBGA, LFBGA, SQFP, TFBGA, VFBGA	not suitable	suitable
HBCC, HBGA, HLQFP, HSQFP, HSOP, HTQFP, HTSSOP, HVQFN, HVSON, SMS	not suitable ⁽³⁾	suitable
PLCC ⁽⁴⁾ , SO, SOJ	suitable	suitable
LQFP, QFP, TQFP	not recommended ⁽⁴⁾⁽⁵⁾	suitable
SSOP, TSSOP, VSO	not recommended ⁽⁶⁾	suitable

Notes

- For more detailed information on the BGA packages refer to the “(LF)BGA Application Note” (AN01026); order a copy from your Philips Semiconductors sales office.
- All surface mount (SMD) packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body size of the package, there is a risk that internal or external package cracks may occur due to vaporization of the moisture in them (the so called popcorn effect). For details, refer to the Drypack information in the “Data Handbook IC26; Integrated Circuit Packages; Section: Packing Methods”.
- These packages are not suitable for wave soldering. On versions with the heatsink on the bottom side, the solder cannot penetrate between the printed-circuit board and the heatsink. On versions with the heatsink on the top side, the solder might be deposited on the heatsink surface.
- If wave soldering is considered, then the package must be placed at a 45° angle to the solder wave direction. The package footprint must incorporate solder thieves downstream and at the side corners.
- Wave soldering is suitable for LQFP, TQFP and QFP packages with a pitch (e) larger than 0.8 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.65 mm.
- Wave soldering is suitable for SSOP and TSSOP packages with a pitch (e) equal to or larger than 0.65 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.5 mm.

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Notes

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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NOTES

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